EXS210009-02

SLED Butterfly 1050nm

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1. SCOPE

1.1 PURPOSE

The purpose of this document is to specify the electro-optical performance and dimensions of superluminescent light emitting diode (SLED).

1.2 RESPONSIBILITY

EXALOS is responsible for establishing, implementing and maintaining this procedure. The Quality representative shall ensure that a timely Engineering Change Notice (ECN) is issued in accordance with EXALOS procedure for any changes.

2. REFERENCE DOCUMENT

- EXS-WI-0001 Visual Inspection Criteria SLED Chip on Submount Procedure
- MIL STD 883 C method.
- Bellcore GR-468-CORE.

3. ELECTRO-OPTICAL PERFORMANCE (T_{SLED} = 25°C)

Parameter	Symbol	Cond.	Min	Typ	Max	Unit
Operating Current	I_{op}				400	mA
Power in SMF	P_o	$I_{op,\ max}$	9	12		mW
Center Wavelength	λ_c	$I_{op,\ max}$	1030	1050	1070	nm
Bandwidth FWHM		$I_{op,\ max}$	60	65		nm
Spectral ripple [RB=0.1nm]		$I_{op,\ max}$		0.1	0.3	dB
Monitor PD Current*	I_{MPD}	$I_{op,\ max}$	0.1			mA
Monitor PD bias voltage			0		-12	V

* Measurement conditions:
- $I_{op} = I_{op}$ Max
- Monitor PD bias voltage: 0 Volts

Input resistance of the Monitor PD current measurement circuit 10 Ohm

4. ABSOLUTE MAXIMUM RATINGS

Stresses beyond the absolute maximum ratings may cause permanent damage to the device.
Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Parameter	Symbol	Cond.	Min	Max	Unit
Forward current	I_F			450	mA
Reverse voltage	V_R			-2	V
Forward voltage	V_F	$I_{F,max}$		2.5	V
Storage temperature	T_{stg}		-40	85	°C
Operating temperature	T_{op}	$I_{F,max}$	-20	65	°C
Storage humidity		<30°C >30°C	5	95 85	% r.h. % r.h.
Thermoelectric cooler voltage	V_{tec}	**		4.0	V
Thermoelectric cooler current	I_{tec}	**		1.8	A
Thermistor Resistance	R_{th}	25°C	10		KΩ
Thermistor constant	B		3892		K
Lead soldering temperature				260	°C
Lead soldering duration				10	s
ESD		human b.m		500	V

** Performance values with hot side temperatures 50°C

5. SCREENING

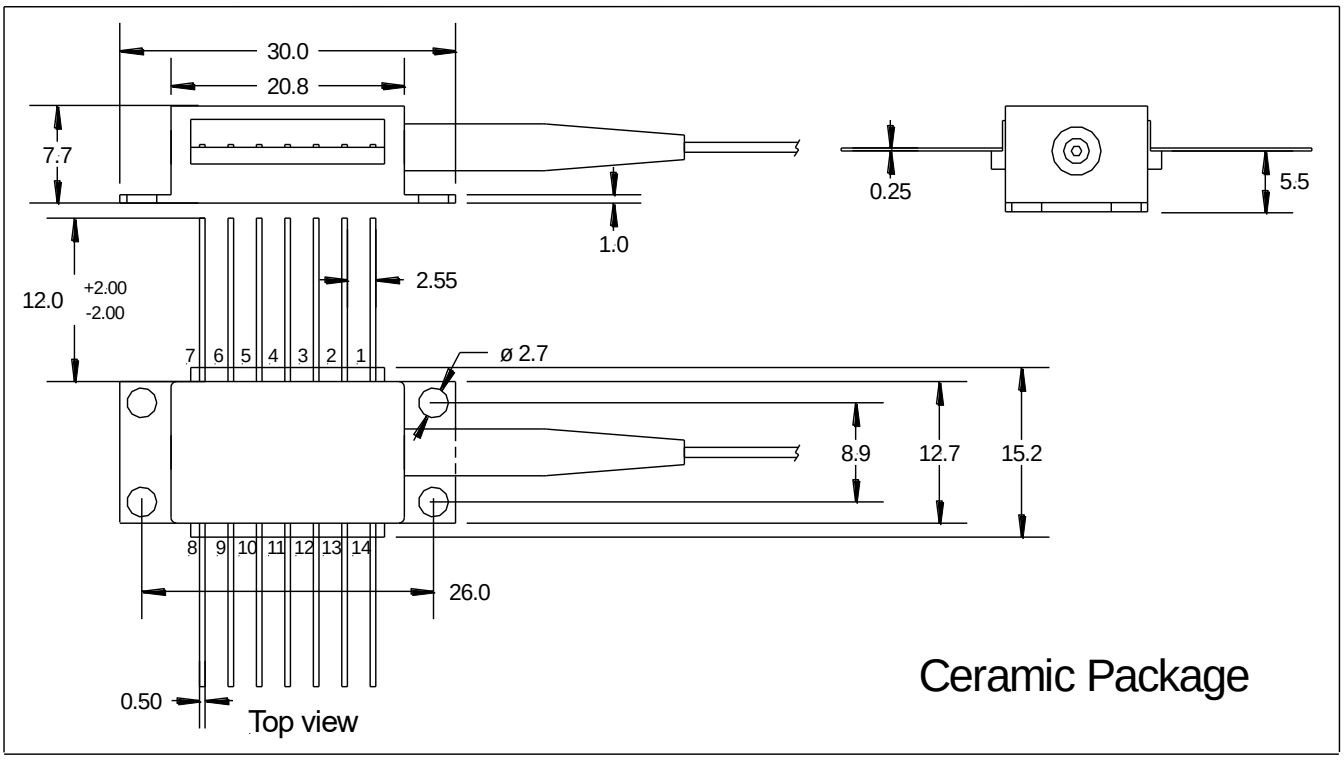
The produced 1050nm SLED Module is required to meet all operating conditions specified in Table 3, Electro-Optical Performance Specifications after being subjected to the following screening tests.

Test Item	Test Conditions	Reference
Seal	Fine: Condition A1 Gross: Condition C	MIL-STD-883, Method 1014 Temperature max 85°C
Temperature Cycling	-40°C to +85°C, ramp rate >= 5°C/min 10 cycles	MIL-STD-883, Method 1010

3rd Angle projection

6. PACKAGE DIMENSIONS [mm]

Tolerances : .X ± 0.25 mm
.XX ± 0.05 mm



Butterfly Package			
Pin	**Function**	**Pin**	**Function**
1	**TEC (+)**	**8**	**NC**
2	**THERMISTOR**	**9**	**NC**
3	**MONITOR DIODE ANODE**	**10**	**SLED ANODE (+)**
4	**MONITOR DIODE CATHODE**	**11**	**SLED CATHODE (-)**
5	**THERMISTOR**	**12**	**NC**
6	**NC**	**13**	**CASE GROUND**
7	**NC**	**14**	**TEC (-)**

7. FIBRE AND CONNECTOR

Part	Description
SM Fibre	SM 6/125µm (Nufern 1060-XP)
Loose tube secondary coating	900 µm
Fiber pigtail length [min]	1 m
Optical connector	FC/APC Narrow Key (2.0mm)

8. IMPORTANT NOTES

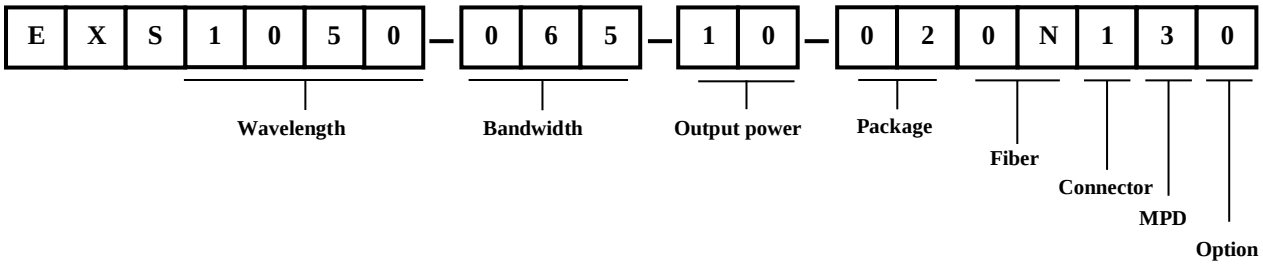
1. Avoid electrostatic discharges, which may destroy the SLED.
2. Never use the SLED module without heat sinking.
3. Adequate eye protection against laser radiation should be used while handling and operating the module.
4. EXALOS declines any responsibility if the device is used in applications where human life may be endangered.
5. Back reflections may influence the output power and spectral characteristics of the SLED. The use of optical isolators and/or angled connectors is recommended. Back reflections of less than -30dB are recommended.
6. The measured optical spectrum of the 1050nm shows absorption lines in the wavelength range from 1000nm to 1200nm which are believed to origin from absorptions in the atmosphere.

9. ORDERING INFORMATION

Please use the following **part number** to order product from EXALOS:

E	X	S	2	1	0	0	0	9	–	0	2

9.1 TECHNICAL DESCRIPTION



10. REVISION HISTORY

Revision History				
Rev.	**Description**	**ECN**	**Date**	**Released**
1.0	Original version	-	07.01.2011	Rezzonico
2.0	Updated specification by new chip design with gaussian shape spectrum, Operating current 400mA and output power ≥ 9mW	EC-01295	14.01.2021	Rezzonico